

UTC UNISONIC TECHNOLOGIES CO., LTD

UP2855

PNP SILICON TRANSISTOR

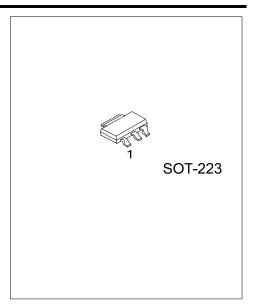
PNP MEDIUM POWER LOW SATURATION TRANSISTOR

DESCRIPTION

The UTC UP2855 is a transistor with low saturation voltage. It provides customers with very low on-state losses that makes it ideal for applications, such as driving and power management functions and DC-DC circuits.

FEATURES

- * Extremely low saturation voltages
- * Peak current up to 10A
- * 4A continuous current

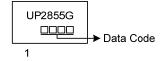


ORDERING INFORMATION

| Ordering Number | Package | Pin Assignment | | | Dooking | |
|-----------------|---------|----------------|---|---|-----------|--|
| | | 1 | 2 | 3 | Packing | |
| UP2855G-AA3-R | SOT-223 | В | С | E | Tape Reel | |

C: Collector E: Emitter Note: Pin Assignment: B: Base UP2855G-AA3-R (1)Packing Type (1) R: Tape Reel (2)Package Type (2) AA3: SOT-223 (3) G: Halogen Free and Lead Free (3)Green Package

MARKING



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■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

| PARAMETER | SYMBOL | RATINGS | UNIT |
|---------------------------------------|------------------|--------------|------|
| Collector-Base Voltage | V_{CBO} | -180 | V |
| Collector-Emitter Voltage | V_{CEO} | -140 | V |
| Emitter-Base Voltage | V_{EBO} | -7 | V |
| Continuous Collector Current (Note 1) | I _C | -4 | А |
| Peak Pulse Current | I _{CM} | -10 | Α |
| Power Dissipation | В | 3.0 (Note 1) | 10/ |
| | P _D | 1.6 (Note 2) | W |
| Junction Temperature | TJ | +150 | °C |
| Storage Temperature | T _{STG} | -55 ~ +150 | °C |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL RESISTANCE

| PARAMETER | SYMBOL | RATINGS | UNIT |
|---------------------|-----------------|-------------|------|
| Junction to Ambient | 0 | 42 (Note 1) | °C/W |
| | θ _{JA} | 78 (Note 2) | |

Notes: 1. For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.

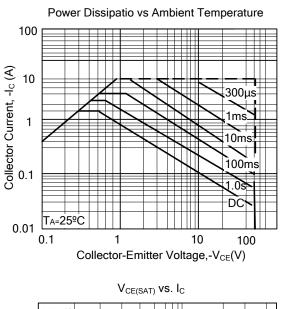
2. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

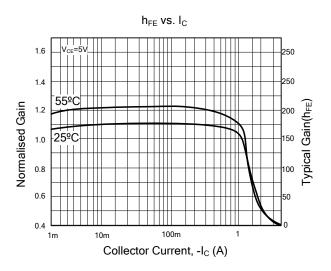
■ ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise stated)

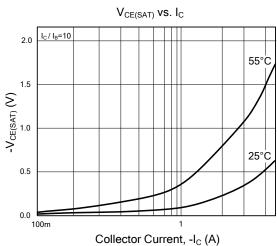
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|----------------------|--|------|------|-------|------|
| Collector-Base Breakdown Voltage | V_{CBO} | I _C =-100μA | -180 | -200 | | V |
| Collector-Emitter Breakdown Voltage | V_{CER} | I _C =-1μA, RB≤1kΩ | -180 | -200 | | V |
| Collector-Emitter Breakdown Voltage | V_{CEO} | I _C =-10mA (Note 1) | -140 | -160 | | V |
| Emitter-Base Breakdown Voltage | V_{EBO} | I _E =-100μA | -7.0 | -8.0 | | V |
| Collector Cut-Off Current | I _{CBO} | V _{CB} =-150V | | <1 | -20 | nA |
| | | V _{CB} =-150V, T _A =100°C | | | -0.5 | μΑ |
| Collector Cut-Off Current | I _{CER} | V _{CB} =-150V, | | <1 | -20 | nA |
| | ICER | R≤1kΩ T _A =100°C | | | -0.5 | μA |
| Emitter Cut-Off Current | I_{EBO} | V _{EB} =-6V | | <1 | -10 | nA |
| Collector-Emitter Saturation Voltage (Note 1) | V _{CE(SAT)} | I _C =-0.1A, I _B =-5mA | | -40 | -60 | mV |
| | | I _C =-0.5A, I _B =-50mA | | -55 | -80 | mV |
| | | I _C =-1A, I _B =-100mA | | -85 | -120 | mV |
| | | I _C =-3A, I _B =-300mA | | -275 | -360 | mV |
| Base-Emitter Saturation Voltage | $V_{BE(SAT)}$ | I _C =-3A, I _B =-300mA(Note 1) | | -940 | -1040 | mV |
| Base-Emitter Turn-On Voltage | $V_{BE(ON)}$ | I _C =-3A, V _{CE} =-5V (Note 1) | | -830 | -930 | mV |
| Static Forward Current Transfer Ratio (Note 1) | h _{FE} | I _C =-10mA, V _{CE} =-5V | 100 | 225 | | |
| | | I _C =-1A, V _{CE} =-5V | 100 | 200 | 300 | |
| | | I _C =-3A, V _{CE} =-5V | 45 | 100 | | |
| | | I _C =-10A, V _{CE} =-5V | | 5 | | |
| Transition Frequency | f⊤ | I _C =-100mA, V _{CE} =-10V f=50MHz | | 120 | | MHz |
| Output Capacitance (Note 1) | Сово | V _{CB} =-10V, f=1MHz | | 33 | | pF |
| | ton | I _C =-1A, V _{CC} =-50V, | | 42 | | |
| Switching Times | t _{OFF} | I _{B1} =-I _{B2} =-100mA | | 636 | | ns |

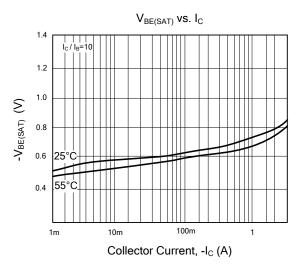
Note: 1. Measured under pulsed conditions. Pulse width≤300µs; duty cycle≤2%.

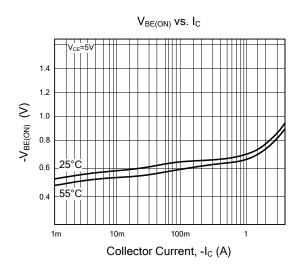
■ TYPICAL CHARACTERISTICS

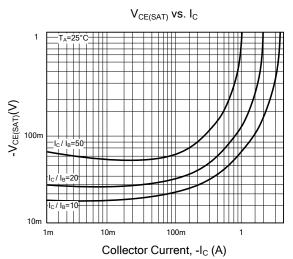












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